

Standard Recovery Diodes (Hockey PUK Version), 1600 A



DO-200AB (B-PUK)


**RoHS
COMPLIANT**
FEATURES

- Wide current range
- High voltage ratings up to 3000 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style DO-200AB (B-PUK)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

PRODUCT SUMMARY

$I_{T(AV)}$	1600 A
Package	DO-200AB (B-PUK)
Circuit configuration	Single diode

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		1600	A
	T_{hs}	55	°C
$I_{F(RMS)}$		3010	A
	T_{hs}	25	°C
I_{FSM}	50 Hz	16 600	A
	60 Hz	17 400	
I^2t	50 Hz	1386	kA ² s
	60 Hz	1265	
V_{RRM}	Range	400 to 3000	V
T_J		-40 to 180	°C

ELECTRICAL SPECIFICATIONS
VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD1500C..L	04	400	500	50
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	25	2500	2600	
	30	3000	3100	



FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at heatsink temperature	$I_{F(AV)}$	180° conduction, half sine wave Double side (single side) cooled		1600 (820)	A
				55 (85)	°C
Maximum RMS forward current	$I_{F(RMS)}$	25 °C heatsink temperature double side cooled		3010	A
Maximum peak, one cycle, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reappplied	16 600	
		t = 8.3 ms		17 400	
		t = 10 ms	100 % V_{RRM} reappplied	14 000	
		t = 8.3 ms		14 700	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied	1386	kA ² s
		t = 8.3 ms		1265	
		t = 10 ms	100 % V_{RRM} reappplied	980	
		t = 8.3 ms		895	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied		13 860	kA ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.83	V
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.95	
Low level value of forward slope resistance	r_{f1}	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.27	mΩ
High level value of forward slope resistance	r_{f2}	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.25	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 3000$ A $T_J = T_J$ maximum, $t_p = 10$ ms sinusoidal wave		1.64	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction operating temperature range	T_J			-40 to 180	°C
Maximum storage temperature range	T_{Stg}			-55 to 200	
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled		0.073	K/W
		DC operation double side cooled		0.031	
Mounting force, ± 10 %				14 700 (1500)	N (kg)
Approximate weight				255	g
Case style		See dimensions - link at the end of datasheet		DO-200AB (B-PUK)	

ΔR_{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	Single Side	Double Side	Single Side	Double Side		
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum	K/W
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.035	0.035	0.036	0.036		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

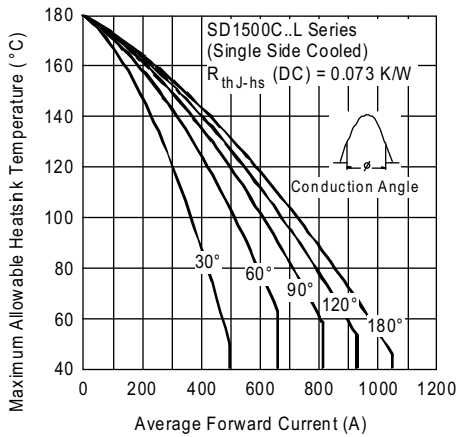


Fig. 1 - Current Ratings Characteristics

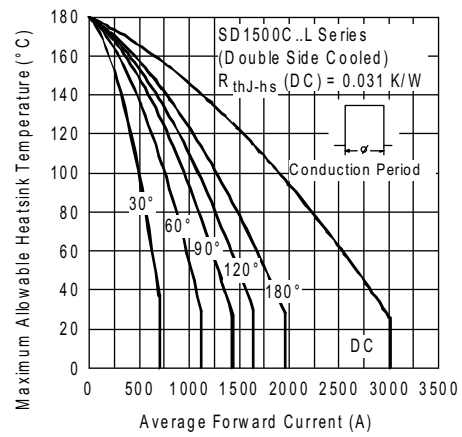


Fig. 4 - Current Ratings Characteristics

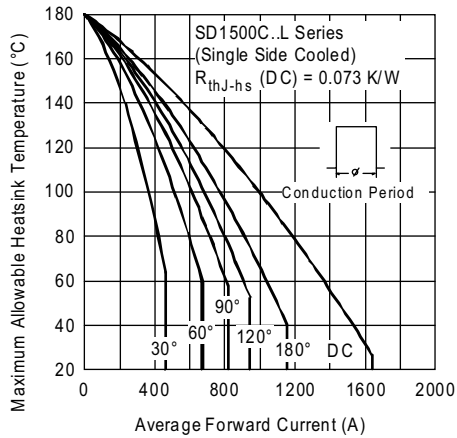


Fig. 2 - Current Ratings Characteristics

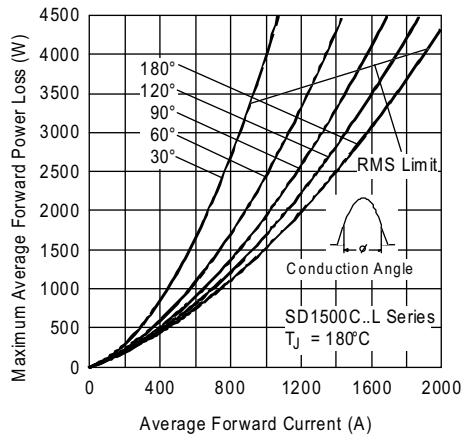


Fig. 5 - Forward Power Loss Characteristics

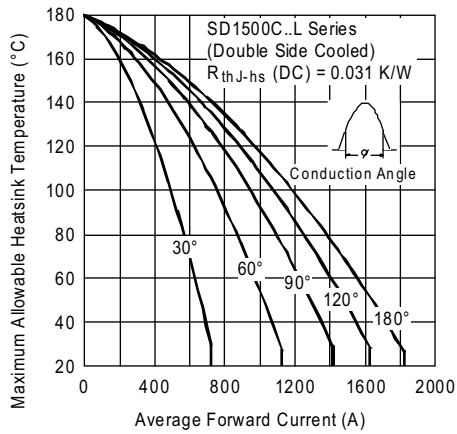


Fig. 3 - Current Ratings Characteristics

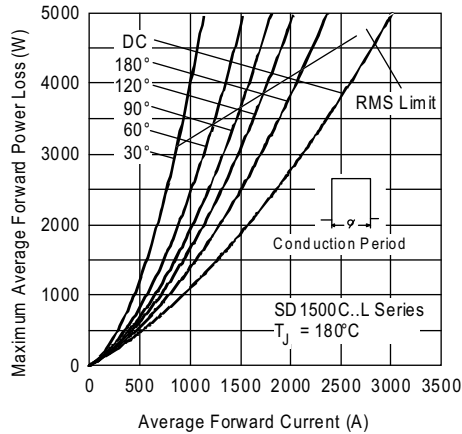


Fig. 6 - Forward Power Loss Characteristics

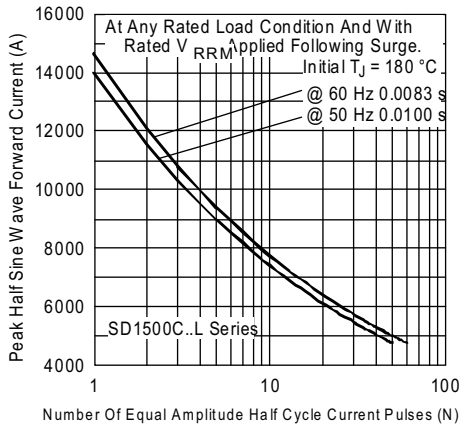


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

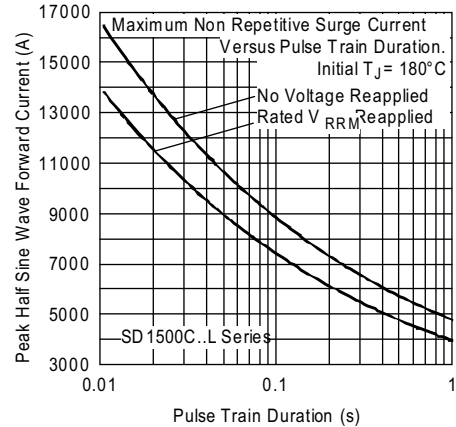


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

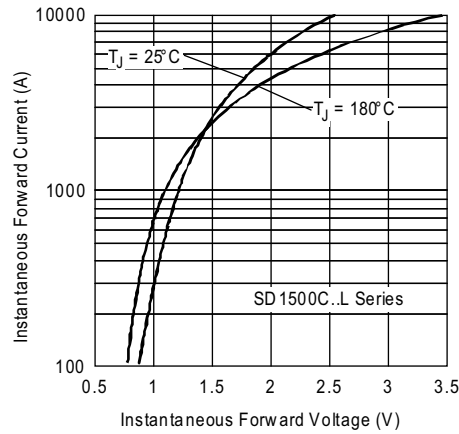


Fig. 9 - Forward Voltage Drop Characteristics

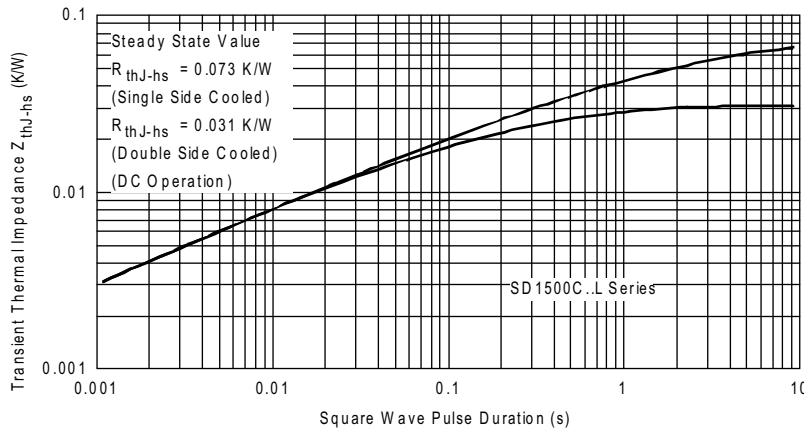
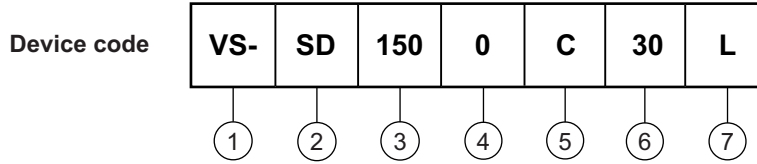


Fig. 10 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

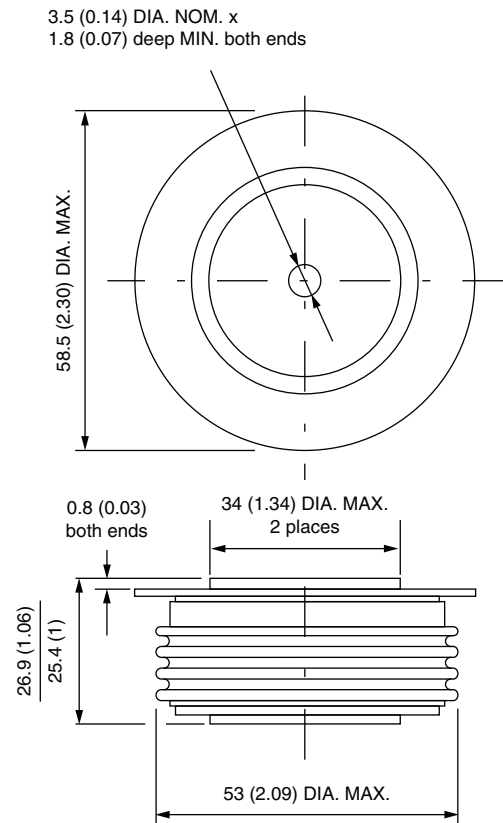


- 1** - Vishay Semiconductors product
- 2** - Diode
- 3** - Essential part number
- 4** - 0 = Standard recovery
- 5** - C = Ceramic PUK
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - L = PUK case DO-200AB (B-PUK)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95246

DO-200AB (B-PUK)

DIMENSIONS in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.